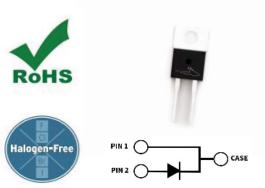


#### 6th Generation 650 V, 20 A Silicon Carbide Schottky Diode

#### **Description**

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher e iciency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.



Package Types: TO-220-2 Marking: O6D20065A

#### **Features**

- Low Forward Voltage  $(V_F)$  Drop with Positive Temperature Coe icient
- Zero Reverse Recovery Ourrent / Forward Recovery Voltage
- Temperature-Independent Switching Behavior

#### **Applications**

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

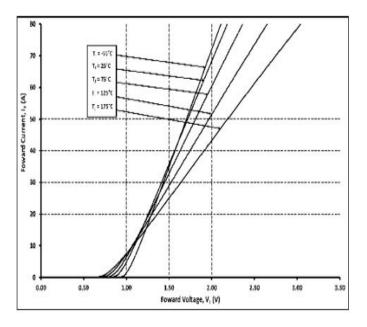
# **Maximum Ratings** ( $T_C = 25^{\circ}C$ Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes
Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	650			
DC Blocking Voltage	V <sub>DC</sub>	650	V		
		66		T <sub>J</sub> = 25 °C	
Continuous Forward Current	I <sub>F</sub>	33		T <sub>J</sub> = 125 °C	Fig. 3
		21	А	T <sub>J</sub> = 150 °C	
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	75		$T_{\rm C} = 25$ °C, $t_{\rm p} = 10$ ms, Half Sine Wave	
		42		$T_{\rm C} = 110$ °C, $t_{\rm p} = 10$ ms, Half Sine Wave	
Non-Repetitive Forward Surge Current	  FSM	125		$T_{\rm C} = 25$ °C, $t_{\rm p} = 10$ ms, Half Sine Wave	Fig. 8
		99		$T_{\rm C} = 110 {\rm ^{\circ}C}$ , $t_{\rm p} = 10 {\rm ms}$ , Half Sine Wave	
Non-Repetitive Peak Forward Surge Current	 F,Max	1475		$T_{\rm C} = 25 {\rm ^{\circ}C},  t_{\rm p} = 10 \mu \rm s,  Pulse$	
		1225		$T_{\rm C} = 110^{\circ}$ C, $t_{\rm p} = 10 \mu$ s, Pulse	
Power Dissipation	P <sub>tot</sub>	166	W	T <sub>J</sub> = 25 °C	Fig. 4
		51		T <sub>J</sub> = 110 °C	
i²t Value	i²t	83	A²s	$T_{c} = 25  {}^{\circ}\text{C}, t_{p} = 10  \text{ms}$	
		51		$T_{c} = 110^{\circ}\text{C}, t_{p} = 10 \text{ ms}$	

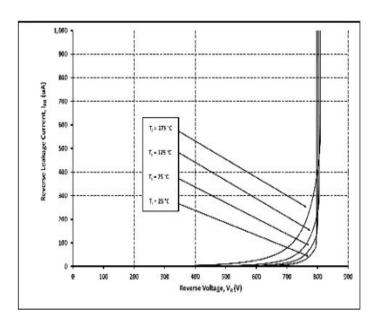
#### **Electrical Characteristics**

Parameter	Symbol	Тур.	Max.	Unit	Test Conditions	Notes
Forward Voltage	.,	1.27	1.50	V	I <sub>F</sub> = 20 A, T <sub>j</sub> = 25 °C	Fig. 1
	V <sub>F</sub>	1.37	1.60		I <sub>F</sub> = 20 A, T <sub>j</sub> = 175 °C	
Reverse Current		5	30	μА	$V_R = 650 \text{ V}, T_j = 25 \text{ °C}$	- F- 0
	I <sub>R</sub>	40	300		$V_{R} = 650 \text{ V}, T_{j} = 175 \text{ °C}$	Fig. 2
Total Capacitive Charge	$Q_{c}$	62		nC	$V_{R} = 400 \text{ V}, T_{j} = 25 \text{ °C}$	Fig. 5
		1153			$V_R = 0 \text{ V}, T_j$	
Total Capacitance	С			pF		

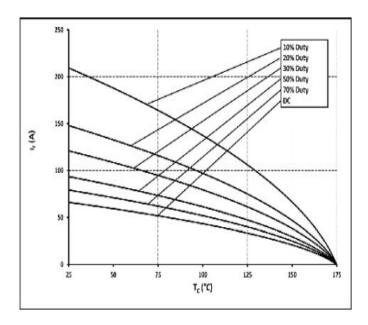
### **Typical Performance**



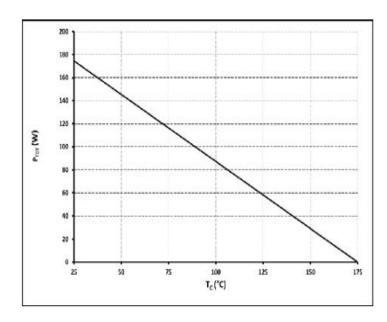
**Figure 1**Forward Characteristics



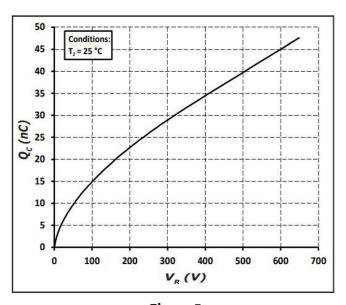
**Figure 2**Reverse Characteristics



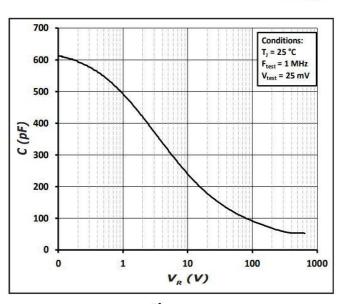
**Figure 3**Current Derating



**Figure 4**Power Derating



**Figure 5**Total Capacitance vs. Reverse Voltage



**Figure 6**Capacitace vs. Reverse Voltage

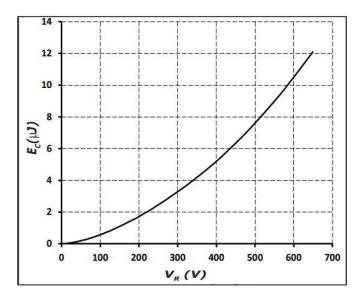
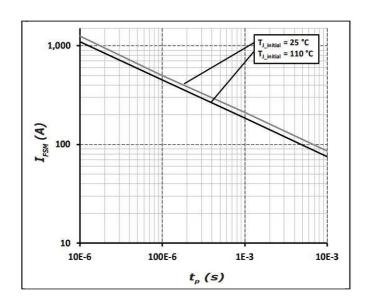


Figure 7
Capacitance Stored Energy



**Figure 8**Non-Repetitive Peak Forward Surge Current versus Pulse Duration (sinusoidal waveform)

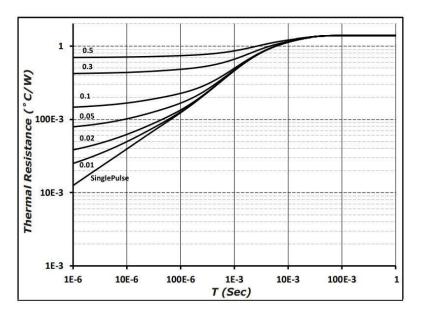
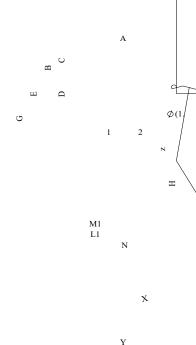


Figure 9
Transient Thermal Impedance

### Package Dimensions & Pin-Out

Package: TO-220-2



NOTE

· 0.20)

В

- 1. ALL METAL SURFACES ARE TIN PLATE EXCEPT AREA OF CUT.
- 2. DIMENSIONING & TOLERANCING CONFOR ASME Y14.5M-1994.
- 3. ALL DIMENSIONS ARE LISTED IN MILLIMETE ANGLES ARE IN DEGREES.
- 4. PACKAGE BURR FLASH SIZE (0.5 mm) IS NOT INCLUDED IN THE DIMENSIONS



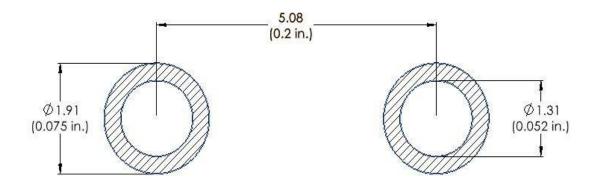
E1 E2

3

ΉH

## **Recommended Solder Pad Layout**

Primary dimensions shown in mm.



## **Product Ordering Information**

Order Number	Packing Type		
C6D20065A	Tube		

## **Revision History**

Document Version	Date of Release	Description of Changes
0	August-2022	Initial Release
1	April-2023	Update Package Drawing Update Landing Pad

#### Notes & Disclaimer

This document and the information contained herein are subject to change without notice. Any such change shall be evidenced by the publication of an updated version of this document by Wolfspeed. No communication from any employee or agent of Wolfspeed or any third party shall e ect an amendment or modification of this document. No responsibility is assumed by Wolfspeed for any infringement of patents or other rights of third parties which may result from use of the information contained herein. No license is granted by implication or otherwise under any patent or patent rights of Wolfspeed.

Notwithstanding any application-specific information, guidance, assistance, or support that Wolfspeed may provide, the buyer of this product is solely responsible for determining the suitability of this product for the buyer's purposes, including without limitation for use in the applications identified in the next bullet point, and for the compliance of the buyers' products, including those that incorporate this product, with all applicable legal, regulatory, and safety-related requirements.

This product has not been designed or tested for use in, and is not intended for use in, applications in which failure

#### **Contact info:**

4600 Silicon Drive Durham, NC 27703 USA Tel: +1.919.313.5300 www.wolfspeed.com/power

© 2022 Wolfspeed, Inc. All rights reserved. Wolfspeed® and the Wolfstreak logo are registered trademarks and the Wolfspeed logo is a trademark of Wolfspeed, Inc. PATENT: https://www.wolfspeed.com/legal/patents

The information in this document is subject to change without notice.